

SEMICONDUCTOR TECHNICAL DATA

KTN2222U/AU EPITAXIAL PLANAR NPN TRANSISTOR

GENERAL PURPOSE APPLICATION.
SWITCHING APPLICATION.

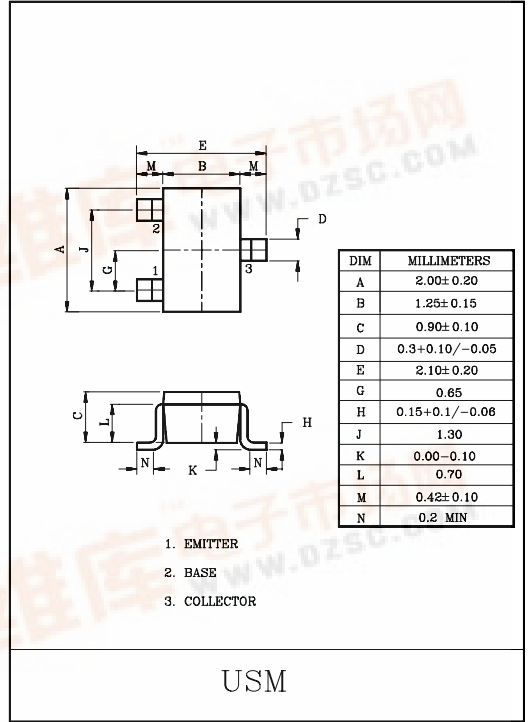
FEATURES

- Low Leakage Current
: $I_{CEX}=10\text{nA}(\text{Max.})$; $V_{CE}=60\text{V}$, $V_{EB(\text{OFF})}=3\text{V}$.
- Low Saturation Voltage
: $V_{CE(\text{sat})}=0.3\text{V}(\text{Max.})$; $I_C=150\text{mA}$, $I_B=15\text{mA}$.
- Complementary to the KTN2907U/2907AU.

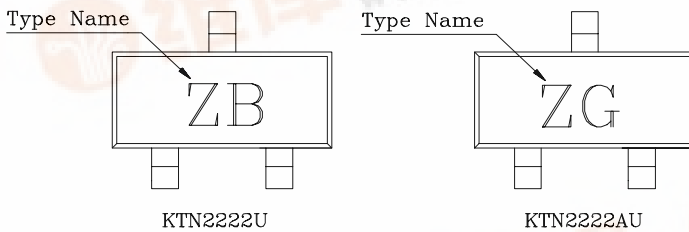
MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING		UNIT
		KTN2222U	KTN2222AU	
Collector-Base Voltage	V_{CBO}	60	75	V
Collector-Emitter Voltage	V_{CEO}	30	40	V
Emitter-Base Voltage	V_{EBO}	5	6	V
Collector Current	I_C	600		mA
Collector Power Dissipation ($T_a=25^\circ\text{C}$)	P_C *	100		mW
Junction Temperature	T_j	150		$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55~150		$^\circ\text{C}$

Note : P_C * : Package Mounted on 99.5% alumina $10 \times 8 \times 0.6\text{mm}$.



Marking



MARK SPEC

TYPE	MARK
KTN2222U	Z B
KTN2222AU	Z G

KTN2222U/AU

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	KTN2222AU	I_{CEX}	$V_{CE}=60V, V_{EB(OFF)}=3V$	-	-	10	nA
Collector Cut-off Current	KTN2222U	I_{CBO}	$V_{CB}=50V, I_E=0$	-	-	0.01	μA
	KTN2222AU		$V_{CB}=60V, I_E=0$	-	-	0.01	
Emitter Cut-off Current	KTN2222AU	I_{EBO}	$V_{EB}=3V, I_C=0$	-	-	10	nA
Collector-Base Breakdown Voltage	KTN2222U	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0$	60	-	-	V
	KTN2222AU			75	-	-	
Collector-Emitter Breakdown Voltage *	KTN2222U	$V_{(BR)CEO}$	$I_E=10mA, I_B=0$	30	-	-	V
	KTN2222AU			40	-	-	
Emitter-Base Breakdown Voltage	KTN2222U	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0$	5	-	-	V
	KTN2222AU			6	-	-	
DC Current Gain *	KTN2222U KTN2222AU	$h_{FE(1)}$	$I_C=0.1mA, V_{CE}=10V$	35	-	-	
		$h_{FE(2)}$	$I_C=1mA, V_{CE}=10V$	50	-	-	
		$h_{FE(3)}$	$I_C=10mA, V_{CE}=10V$	75	-	-	
		$h_{FE(4)}$	$I_C=150mA, V_{CE}=10V$	100	-	300	
	KTN2222U KTN2222AU	$h_{FE(5)}$	$I_C=500mA, V_{CE}=10V$	30	-	-	
				40	-	-	
Collector-Emitter Saturation Voltage *	KTN2222U KTN2222AU	$V_{CE(sat)1}$	$I_C=150mA, I_B=15mA$	-	-	0.4	V
				-	-	0.3	
	KTN2222U KTN2222AU	$V_{CE(sat)2}$	$I_C=500mA, I_B=50mA$	-	-	1.6	
				-	-	1	
Base-Emitter Saturation Voltage *	KTN2222U KTN2222AU	$V_{BE(sat)1}$	$I_C=150mA, I_B=15mA$	-	-	1.3	V
				0.6	-	1.2	
	KTN2222U KTN2222AU	$V_{BE(sat)2}$	$I_C=500mA, I_B=50mA$	-	-	2.6	
				-	-	2.0	
Transition Frequency	KTN2222U KTN2222AU	f_T	$I_C=20mA, V_{CE}=20V, f=100MHz$	250	-	-	MHz
				300	-	-	
Collector Output Capacitance		C_{ob}	$V_{CB}=10V, I_E=0, f=1.0MHz$	-	-	8	pF
Input Capacitance	KTN2222U	C_{ib}	$V_{EB}=0.5V, I_C=0, f=1.0MHz$	-	-	30	pF
	KTN2222AU			-	-	25	

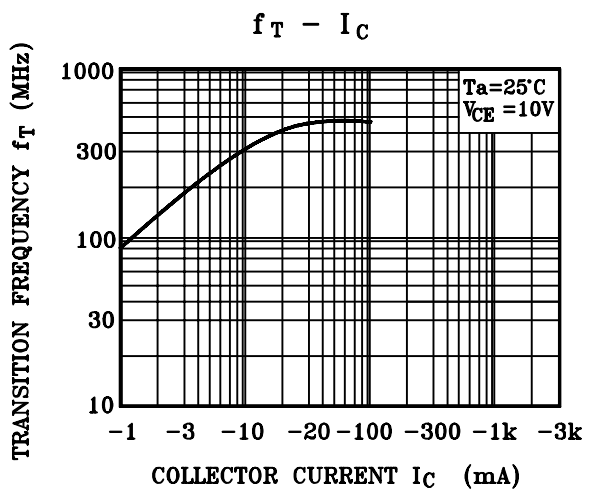
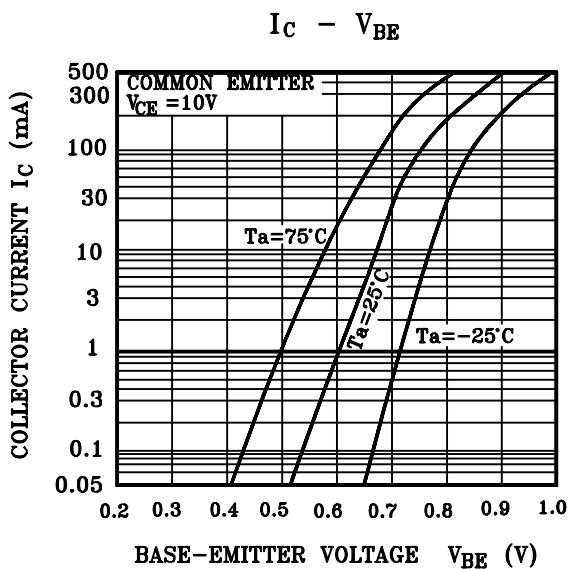
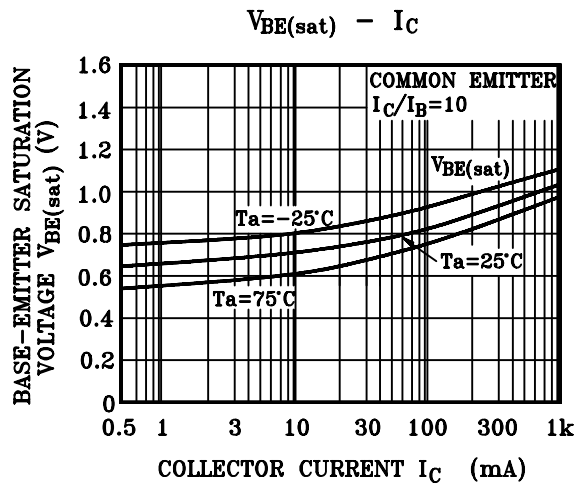
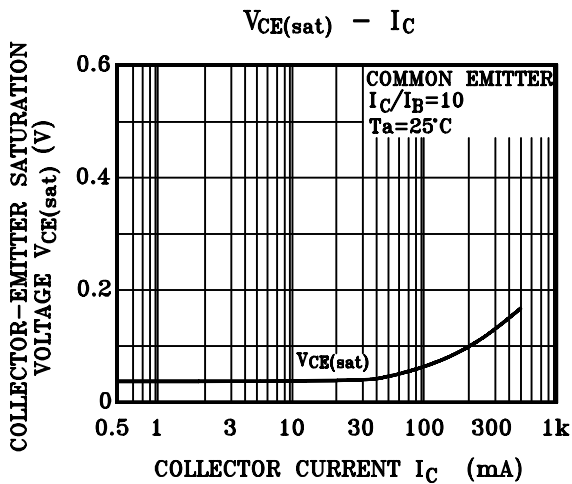
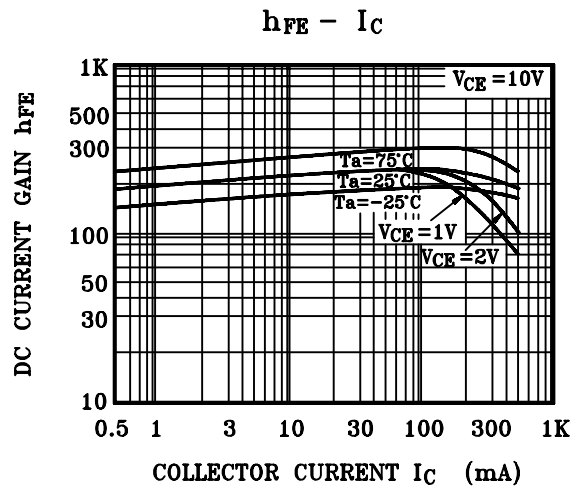
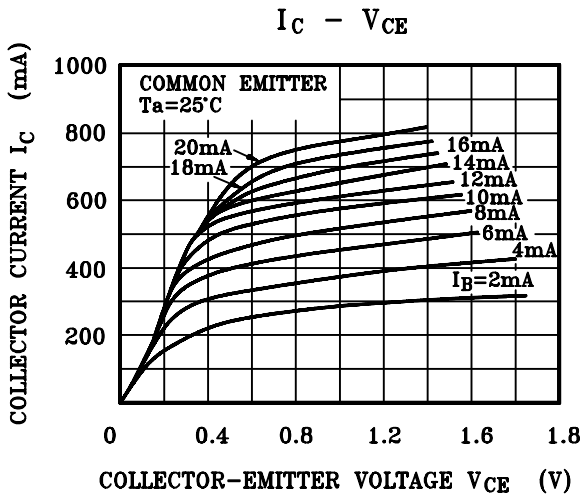
Note : *Pulse Test : Pulse Width $\leq 300\mu S$, Duty Cycle $\leq 2.0\%$

KTN2222U/AU

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Impedance	KTN2222AU	h_{ie}	$I_C=1mA, V_{CE}=10V, f=1kHz$	2	-	8	$k\Omega$
			$I_C=10mA, V_{CE}=10V, f=1kHz$	0.25	-	1.25	
Voltage Feedback Ratio	KTN2222AU	h_{re}	$I_C=1mA, V_{CE}=10V, f=1kHz$	-	-	8	$\times 10^{-4}$
			$I_C=10mA, V_{CE}=10V, f=1kHz$	-	-	4	
Small-Signal Current Gain	KTN2222AU	h_{fe}	$I_C=1mA, V_{CE}=10V, f=1kHz$	50	-	300	
			$I_C=10mA, V_{CE}=10V, f=1kHz$	75	-	375	
Collector Output Admittance	KTN2222AU	h_{oe}	$I_C=1mA, V_{CE}=10V, f=1kHz$	5	-	35	μS
			$I_C=10mA, V_{CE}=10V, f=1kHz$	25	-	200	
Collector-Base Time Constant	KTN2222AU	$C_c \cdot r_{bb}'$	$I_E=20mA, V_{CB}=20V, f=31.8MHz$	-	-	150	pS
Noise Figure	KTN2222AU	NF	$I_C=100\mu A, V_{CE}=10V, R_g=1k\Omega, f=1kHz$	-	-	4	dB
Switching Time	Delay Time	t_d	$V_{CC}=30V, V_{BE(OFF)}=0.5V, I_C=150mA, I_{B1}=15mA$	-	-	10	nS
	Rise Time	t_r		-	-	25	
	Storage Time	t_{stg}	$V_{CC}=30V, I_C=150mA, I_{B1}=I_{B2}=15mA$	-	-	225	
	Fall Time	t_f		-	-	60	

KTN222U/AU



KTN222U/AU

